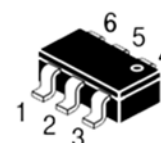
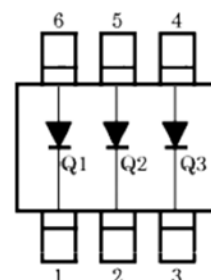


Schottky Barrier Diode



Features:

- Low Forward Voltage Drop
- Guard Ring Construction for Transient Protection
- Fast Switching
- Low Leakage Current
- Three Fully Isolated Schottky Diode
- Also Available in Lead Free Version



SOT-363

Applications:

High speed switching

Maximum Rating @ T_A = 25°C unless otherwise specified

Parameter	Symbol	SD103ATW-7-F	Unit
Peak repetitive reverse voltage Working peak reverse voltage DC blocking voltage	V_{RRM} V_{RWM} V_R	40	V
RMS reverse voltage	$V_{R(RMS)}$	28	V
Forward continuous current (Max.)	I_F	350	mA
Average rectified current	I_O	175	mA
Non-Repetitive peak forward surge current @t ≤ 10ms	I_{FSM}	1	A
Thermal resistance, junction to ambient air	$R_{\theta JA}$	500	°C/W
Power dissipation	P_D	200	mW
Junction and storage temperature	T_j, T_{stg}	-55 to +125	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

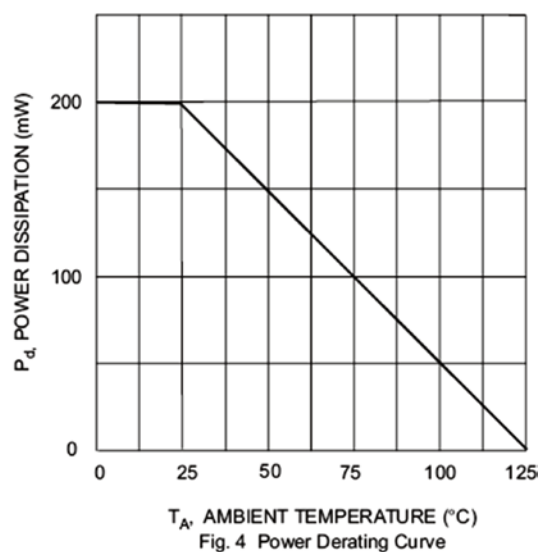
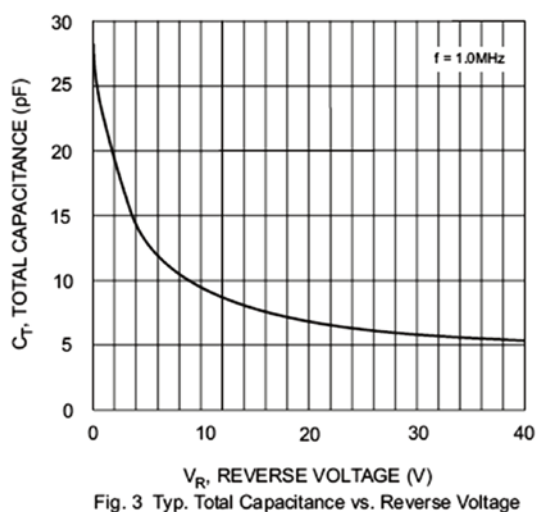
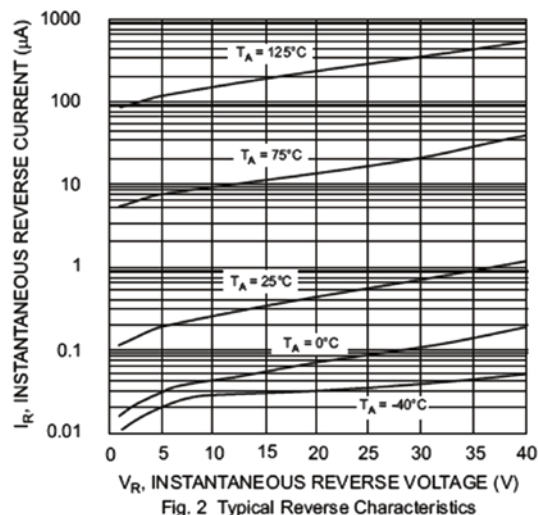
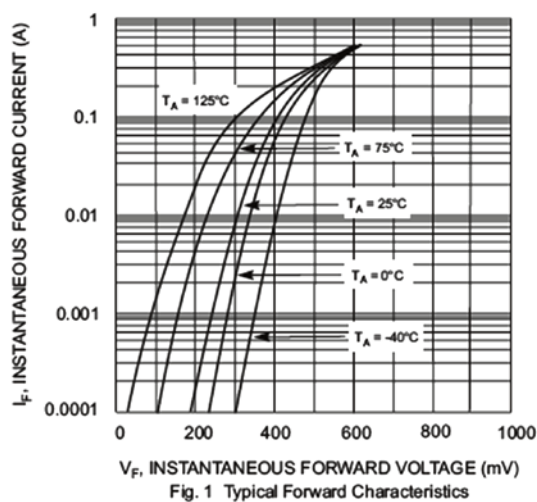
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse breakdown voltage	$V_{(BR)R}$	$I_R = 100\mu A$	40		-	V
Average reverse current	I_R	$V_R = 10V$ $V_R = 30V$		0.2 0.4	2 5	μA

Schottky Barrier Diode



Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Forward voltage	V_F	$I_F = 1\text{mA}$ $I_F = 5\text{mA}$ $I_F = 20\text{mA}$ $I_F = 100\text{mA}$	-	0.27 0.32 0.36 0.44	0.37 0.5	V
Total capacitance	C_T	$V_R = 0\text{V}, f = 1\text{MHz}$	-	50	-	pF
Reverse recovery time	t_{rr}	$I_F = I_R = 200\text{mA}, I_{rr} = 0.1 \cdot I_R$ $R_L = 100\Omega$	-	10	-	ns

Typical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

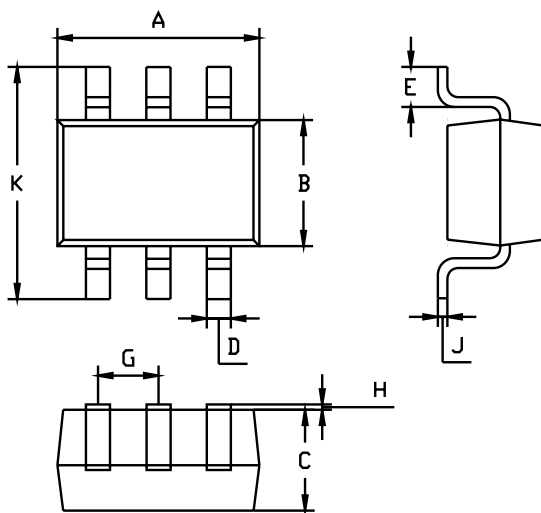


Schottky Barrier Diode



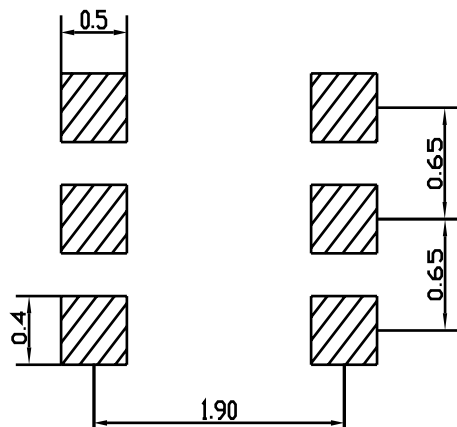
Package Outline

Plastic surface mounted package



SOT-363		
Dim	Min	Max
A	1.8	2.2
B	1.15	1.35
C	1 Typical	
D	0.10	0.30
E	0.25	0.40
G	0.65 Typical	
H	0.02	0.10
J 0	.1 Typical	
K	2.1	2.3
All Dimensions in mm		

Soldering Footprint



Dimensions : Millimetres

Package Information

Device	Package	Shipping
SD103ATW-7-F	SOT-363	3,000/Tape & Reel

Part Number Table

Description	Part Number
Schottky Barrier Diode	SD103ATW-7-F

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